Attorney's Docket No.: 12732-051002 / US4976/4978/4981/4982D1

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Shunpei Yamazaki, et al.

Art Unit :

Unknown

Serial No.: New Application

Examiner:

Unknown

Filed

: December 5, 2003

Confirmation No.:

Unknown

Title

: THIN FILM TRANSISTORS AND SEMICONDUCTOR DEVICE

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Under 35 USC §120, this application relies on the earlier filing date of application serial number 09/874,204, filed on June 6, 2001. The attached list of references were submitted to and/or cited by the Office in the prior application and, therefore, are not provided in this application.

This statement is being filed with the application. Please apply any charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

Date: December 5, 2003

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nt of Commerce Attorney's Docket No. rademark Office 12732-051002

Application No. New Application

Information Disclosure Statement by Applicant (Use several sheets if necessary)

Applicant Shunpei Yamazaki, et al.

Group Art Unit

(37 CFR §1.98(b))

Filing Date December 5, 2003

Unknown

			U.S. Patent	Documents			
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
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Examiner Signature	Date Considered
EVALUATED 1-31-1-31-1-31-1-31-1-31-1-31-1-31-1-3	
EXAMINER: Initials citation considered. Draw line through citation if no	t in conformance and not considered. Include convert this form with

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	b	Disclosure Stary Applicant		Applicant Shunpei Yamazaki, et al.				
(Use several sheets if necessary) (37 CFR §1.98(b))			Filing Date December 5, 2003	Group Art Unit Unknown	1 '			
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Examiner Signature	Date Considered				
EXAMINER: Initials citation considered. Drawline through citation if no	t in conformance and not considered. Include conv of this form with				

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